AUTOMOTIVE GRADE

> COMPLIANT HALOGEN

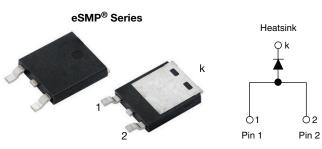
FREE



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Vishay Semiconductors

Hyperfast Rectifier, 8 A FRED Pt®



SlimDPAK (TO-252AE)

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	8 A			
V _R	600 V			
V _F at I _F	1.4 V			
t _{rr} (typ.)	14 ns			
T _J max.	175 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Single			

FEATURES

- Hyperfast recovery time, extremely Q_{rr} recovery
- For PFC CCM operation
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
 - meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	I _{F(AV)}	T _C = 140 °C	8	۸
Non-repetitive peak surge current	I _{FSM}	$T_J = 25$ °C, 10 ms sine pulse wave	80	A
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	Ι _R = 100 μΑ	600	-	-	,,
Commend wells are	V	I _F = 8 A	-	2.3	3.0	V
Forward voltage	V _F	I _F = 8 A, T _J = 150 °C	-	1.4	1.8	
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	20	μА
		$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	500	
Junction capacitance	C _T	V _R = 600 V	-	12	-	pF

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1 \text{ A, } dI_F/dt = 50 \text{ A/}\mu\text{s, } V_R = 30 \text{ V}$		-	20	-	
		$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	14	-	
Reverse recovery time		$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{RR} = 0.25 \text{ A}$		-	-	18	ns
		T _J = 25 °C	I _F = 8 A dI _F /dt = 500 A/μs V _R = 400 V	-	20	-	- A
		T _J = 125 °C		-	54	-	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	4.0	-	
		T _J = 125 °C		-	8.0	-	
Payaraa raaayary aharaa	Q_{rr}	T _J = 25 °C		-	60	-	nC
Reverse recovery charge		T _J = 125 °C		-	200	=	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	ı	175	°C
Thermal resistance, junction to mount	R_{thJM}		-	-	2.2	°C/W
Weight			-	0.20	-	g
Marking device		Case style SlimDPAK (TO-252AE)		8EV	′X06	

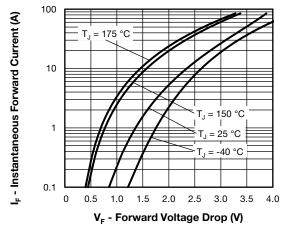


Fig. 1 - Typical Forward Voltage Drop Characteristics

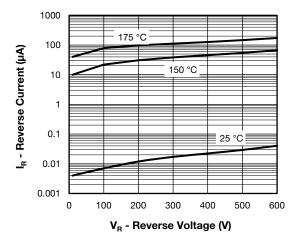


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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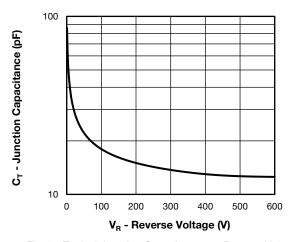


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

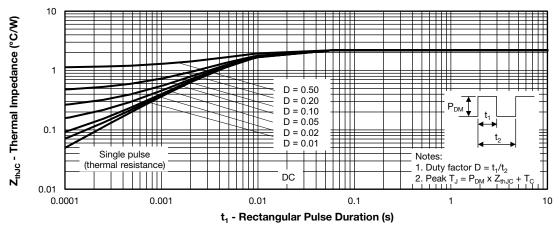


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

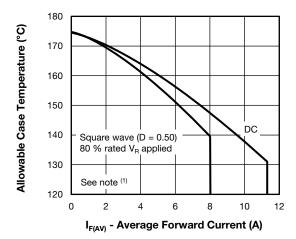


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

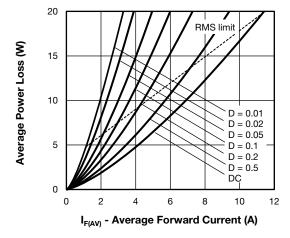


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

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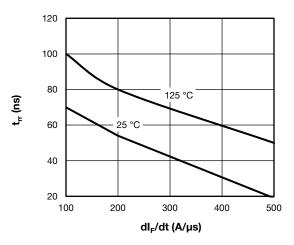


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

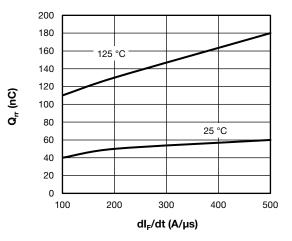
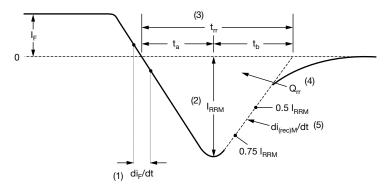


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_r$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

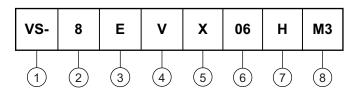
Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (8 = 8 A)
- 3 Circuit configuration:
 - E = single die
- V = SlimDPAK
- 5 Process type: X = hyperfast rectifier
 - Voltage code (06 = 600 V)
- 7 H = AEC-Q101 qualified
- 8 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-8EVX06HM3/I	0.20	I	4500	13"diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?96081</u>			
Part marking information	www.vishay.com/doc?96085		
Packaging information	www.vishay.com/doc?88869		

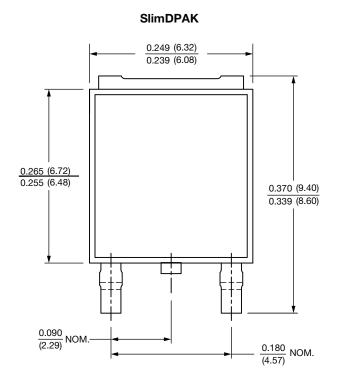


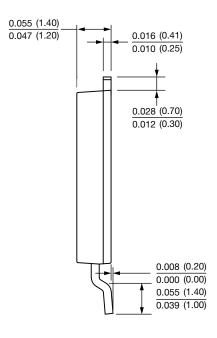


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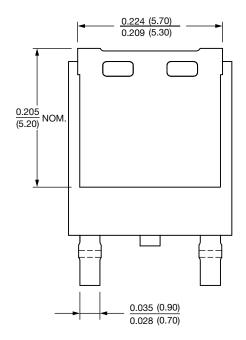
SlimDPAK

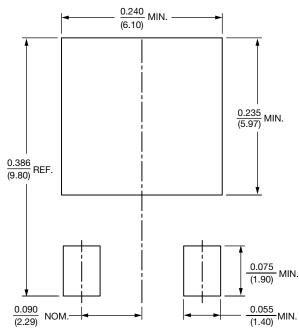
DIMENSIONS in inches (millimeters)





Mounting Pad Layout





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